Research Article

Thermal Characterization of the Overload Carbon Resistors

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In many applications, the electronic component is not continuously but only intermittently overloaded (e.g., inrush current, short circuit, or discharging interference). With this paper, we provide insight into carbon resistors that have to hold out a rarely occurring transient overload. Using simple electrical circuit, the resistor is overheating with higher current than declared, and dissipation is observed by a thermal camera.

1. Introduction

The electronic designers must be sure that the correct device is chosen on the basis of both electrical and thermal performances. Many companies have established their own standards and testing techniques based on their experience, but often this information is not enough. It is necessary to know the operating life of electronic components affected by temperature and voltage stress. Measurement and temperature control are becoming increasingly important especially since device and electronic board sizes are shrinking.

Temperature measurement is not easy but is necessary since it is the only measurable parameter for the quality of the thermal design [1]. Every electronic component requires dedicated approaches according to its specific functionality.

One of the most frequently used electronic components is resistor. Resistor can be connected in various networks where it acts as voltage dropper, voltage divider, or current limiter. Resistors reduce the voltage or current signal passing through them. A higher voltage makes the electrons move faster through resistor and it warms up the resistor. As a result, energy is turned into heat. Typical values for this parameter are 1/16 W, 1/10 W, 1/8 W, 1/4 W, 1/2 W, 1 W, 2 W, 2.5 W, 3 W, or higher to 100 W or even 300 W. For the thermal problem, given that energy is not the only restriction parameter, the temperature will increase faster reducing the size of the resistor because the power dissipation capability is directly proportional to size. Also, a system that will reduce the temperature rise of electronic parts and equipment is necessary [2].

2. Experimental Setup

Measurements were performed by heating the resistor by electric current. The propagation of the heat is a physical process and depends on the thermal properties of materials, size of the area, and length of the wire. Because of the small area of the resistor, contact methods can easily change the value of surface temperature. So this method is worthless for this kind of measurements [3]. Most of the light is radiated at infrared (IR) wavelengths, but at sufficiently high temperatures there is a considerable amount of light also at visible wavelengths. This amount of radiated heat energy has \( \sim T^4 \) dependency assuming that it is by natural convection [4, 5].

In this experiment, it is not important to know the exact temperature of the resistor, but rather how fast temperature rises and its influence on resistor. The process is observed by an infrared camera. In this case, we used FLIR SC 620 camera, manufactured by FLIR Systems. With an operational range of 7.5 \( \mu \)m–13 \( \mu \)m band at temperatures between 0°C and +500°C, it is equipped with a 45° lens and enables capturing structures by FPA (focal plane array) microbolometer set to a rate of 120 frames per second. The major technical specifications of the camera used in this study are listed in Table 1. The readout
temperature is proportional to the IR flux coming from the scene. The main components of the signal are the thermal radiation emitted by the object (assumed to be an opaque grey body), the thermal radiation emitted by the heater, and the background radiation reflected from the object surface.

Test circuit board is very simple because of thermal spreading. The heat generated from a localized hot spot will eventually reach thermal equilibrium with its environment to minimize temperature gradients. The temperature distribution is completely different on an isolated resistor than in circuit with couple resistors. It consists of MOSFET BD135 that controls input signal as it is shown in Figure 1 and 75 Ohm carbon resistor of 1/4 W which simulates electronic circuit with pulse excitation. In this case, MOSFET has a role of voltage regulator [6]. Resistor has a ceramic substrate which normally holds the resistor together during and after firing, so the resistor can be fired at least twice as it is tried in this experiment. It is calculated from the input signals that the maximum reached power can be 3 W and 12 W which is more than declared. Thermal characteristics of MOSFET BD135, which is used in this experiment, are given in Table 2 [7].

MOSFET is connected to a source supplying 15 V or 30 V. Voltage through resistor (shown in Figure 1) is monitored by Rigol oscilloscope.

Using a thermal camera and an oscilloscope to observe the voltage and current through the resistor, we can gain an understanding of how a hot spot develops on the surface of the resistor. Data recording began by turning on the thermal camera and starting its Researcher software on computer (Figure 2).

The main interest of this experiment is temperature change, so we set up emission of the resistor to $\varepsilon = 0.96$, distance to 0.1 m, and temperature reflectance to 8°C.

Observed heat is higher than preferred value ranges and carbon resistor is discoloured soon (Figure 3). Five minutes after heating, we checked resistance and it has not changed; it was within the margin of the error (error is 5% as the manufacturer declared).

Also, after we had stopped the heating, we checked the resistance when the thermal camera showed a temperature of 100°C and it was within the limits of error. Heat dissipation
is high and the resistor does not lose its resistance, but it has an influence on the board and on the other components at the board. After pulse excitation, when surface temperature of resistor was near 50°C, we noticed that resistor was cooling faster than some points of the board [8–10].

The process of heating is very fast because the resistors were heating by current 10 times higher than it is declared. Temperature was changing very fast, so it was necessary to use fast thermal camera for measurements [8]. Because of the small dimension of a resistor, it is impossible to measure temperature transition by contact methods. Each test runs for 1-2 minutes after turning on the test circuit. Resistor temperature profiles were monitored from 3 different aspects as it is shown in Figure 4.

### 3. Results and Discussion

In Figure 5(a), steady-state condition is reached in a short time after 10–15 seconds. It is shown that the maximum temperature is reached in the centre of the resistor as it was expected (red curve) [9–11]. Red and green curves represent temperature profiles taken from LI02 and LI04 lines as it is shown in Figure 4(a). Internal parameters of the resistor lead to changes in maximum generated power [12,13]. It is important to study the variation of power from a technological point of view. In recent papers, the efficiency and properties in terms of various conditions have been observed [14, 15].

Line LI01 in Figure 4(b) represents temperature profile of the resistor taken from one frame as proof of different heat distribution as it is shown in Figure 5(b).

During testing, we wanted to know the temperature profile for the resistor in DC current circuit (Figure 6). Temperature profile is observed at lines in Figure 4(a) (LI02 and LI04) during excitation.

### 4. Conclusion

The limiting temperatures are those which the constituents can withstand before they oxidize, melt, or change value. The idea that there is a nonuniform distribution of temperature is demonstrated. The resistors used in this test showed excellent flame resistance. It is shown that thermography can be used during addition testing. Thermography can be used as noncontact method because it gives temperature distribution in more than a couple of points and because, in the short time, a set of measurements can be done. Because of the small area of the resistor, contact methods can easily change value of
surfacetemperature. So this method is worthless for this kind of measurements.

Also, it has been noticed that the resistor was cooling faster than some points of the board. Heat conduction of the resistor has an influence on the board and on the other components at the board which can be damaged, which can be the subject of the next research. The system must be considered by many aspects and that is why it is necessary to have cooling system or to pay more attention to construction of board.

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References


